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February 2007

# **FAN7382**

# **High- and Low-Side Gate Driver**

#### **Features**

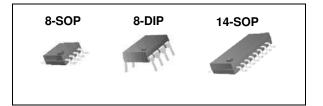
- Floating Channels Designed for Bootstrap Operation to +600V
- Typically 350mA/650mA Sourcing/Sinking Current Driving Capability for Both Channels
- Common-Mode dv/dt Noise Canceling Circuit
- Extended Allowable Negative V<sub>S</sub> Swing to -9.8V for Signal Propagation at V<sub>CC</sub>=V<sub>BS</sub>=15V
- V<sub>CC</sub> & V<sub>BS</sub> Supply Range from 10V to 20V
- UVLO Functions for Both Channels
- TTL Compatible Input Logic Threshold Levels
- Matched Propagation Delay Below 50nsec
- Output In-phase with Input Signal

## **Applications**

- PDP Scan Driver
- Fluorescent Lamp Ballast
- SMPS
- Motor Driver

### **Description**

The FAN7382, a monolithic high and low side gate-drive IC, can drive MOSFETs and IGBTs that operate up to +600V. Fairchild's high-voltage process and common-mode noise canceling technique provides stable operation of the high-side driver under high-dv/dt noise circumstances. An advanced level-shift circuit allows high-side gate driver operation up to  $V_{\rm S}$ -9.8V (typical) for  $V_{\rm BS}$ =15V. The input logic level is compatible with standard TTL-series logic gates. UVLO circuits for both channels prevent malfunction when  $V_{\rm CC}$  or  $V_{\rm BS}$  is lower than the specified threshold voltage. Output drivers typically source/sink 350mA/650mA, respectively, which is suitable for fluorescent lamp ballasts, PDP scan drivers, motor controls, etc.



# **Ordering Information**

Part Number	Package	Pb-Free	<b>Operating Temperature Range</b>	Packing Method	
FAN7382N	8-DIP		-40°C ~ 125°C	Tube	
FAN7382M <sup>(1)</sup>	8-SOP	Yes		Tube	
FAN7382MX <sup>(1)</sup>	0-3OF			Tape & Reel	
FAN7382M1 <sup>(1)</sup>	14-SOP			Tube	
FAN7382M1X <sup>(1)</sup>	14-30F			Tape & Reel	

#### Note:

1. These devices passed wave soldering test by JESD22A-111.

# **Typical Application Circuit**

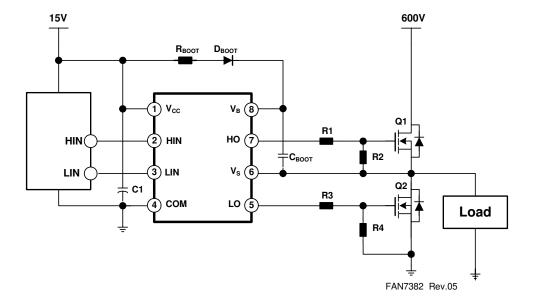


Figure 1. Application Circuit for Half-Bridge

# **Internal Block Diagram**

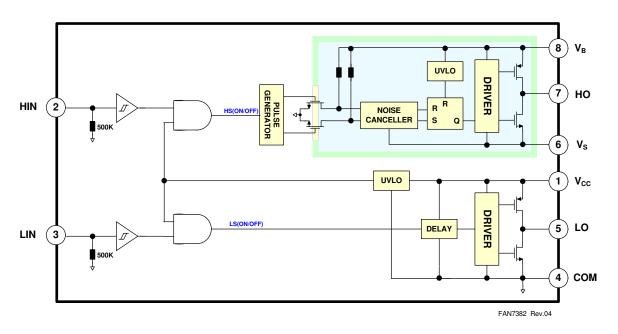


Figure 2. Functional Block Diagram

# **Pin Assignments**

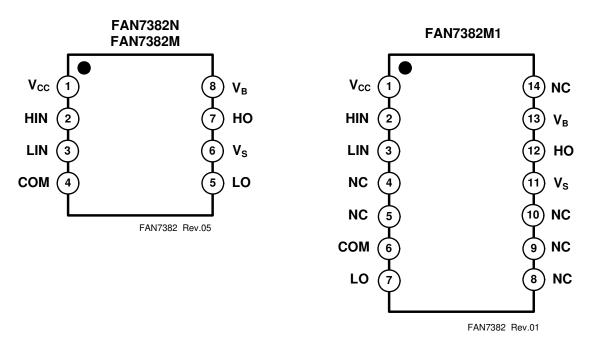


Figure 3. Pin Configuration (Top View)

# **Pin Definitions**

Name	Description		
V <sub>CC</sub>	Low-Side Supply Voltage		
HIN	Logic Input for High-Side Gate Driver Output		
LIN	Logic Input for Low-Side Gate Driver Output		
COM	Logic Ground and Low-Side Driver Return		
LO	Low-Side Driver Output		
V <sub>S</sub>	High-Voltage Floating Supply Return		
НО	High-Side Driver Output		
V <sub>B</sub>	High-Side Floating Supply		

# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Characteristics	Min.	Max.	Unit
V <sub>S</sub>	High-side offset voltage	V <sub>B</sub> -25	V <sub>B</sub> +0.3	
V <sub>B</sub>	High-side floating supply voltage	-0.3	625	
V <sub>HO</sub>	High-side floating output voltage HO	V <sub>S</sub> -0.3	V <sub>B</sub> +0.3	
V <sub>CC</sub>	Low-side and logic fixed supply voltage	-0.3	25	V
$V_{LO}$	Low-side output voltage LO	-0.3	V <sub>CC</sub> +0.3	]
V <sub>IN</sub>	Logic input voltage (HIN, LIN)	-0.3	V <sub>CC</sub> +0.3	]
COM	Logic ground	V <sub>CC</sub> -25	V <sub>CC</sub> +0.3	]
dV <sub>S</sub> /dt	Allowable offset voltage slew rate		50	V/ns
	Power dissipation	8-SOP	0.625	
$P_D^{(2)(3)(4)}$		14-SOP	1.0	W
		8-DIP	1.2	]
	Thermal resistance, junction-to-ambient	8-SOP	200	
$\theta_{\sf JA}$		14-SOP	110	°C/W
		8-DIP	100	1
$T_J$	Junction temperature		150	°C
T <sub>STG</sub>	Storage temperature		150	°C

#### Notes:

- 2. Mounted on 76.2 x 114.3 x 1.6mm PCB (FR-4 glass epoxy material).
- 3. Refer to the following standards:
  - JESD51-2: Integral circuits thermal test method environmental conditions natural convection JESD51-3: Low effective thermal conductivity test board for leaded surface mount packages
- 4. Do not exceed P<sub>D</sub> under any circumstances.

# **Recommended Operating Ratings**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit	
V <sub>B</sub>	High-side floating supply voltage	V <sub>S</sub> +10	V <sub>S</sub> +20		
V <sub>S</sub>	High-side floating supply offset voltage	6-V <sub>CC</sub>	600		
V <sub>HO</sub>	High-side (HO) output voltage	V <sub>S</sub>	V <sub>B</sub>	V	
V <sub>LO</sub>	Low-side (LO) output voltage	COM	V <sub>CC</sub>	V	
V <sub>IN</sub>	Logic input voltage (HIN, LIN)	COM	V <sub>CC</sub>		
V <sub>CC</sub>	Low-side supply voltage	10	20		
T <sub>A</sub>	Ambient temperature	-40	125	°C	

#### **Electrical Characteristics**

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ )=15.0V,  $T_A$  = 25°C, unless otherwise specified. The  $V_{IN}$  and  $I_{IN}$  parameters are referenced to COM. The  $V_O$  and  $I_O$  parameters are referenced to  $V_S$  and COM and are applicable to the respective outputs HO and LO.

Symbol	Characteristics	Test Condition	Min.	Тур.	Max.	Unit
V <sub>CCUV+</sub> V <sub>BSUV+</sub>	V <sub>CC</sub> and V <sub>BS</sub> supply under-voltage positive going threshold		8.2	9.2	10.0	
V <sub>CCUV-</sub> V <sub>BSUV-</sub>	V <sub>CC</sub> and V <sub>BS</sub> supply under-voltage negative going threshold		7.6	8.7	9.6	V
V <sub>CCUVH</sub> V <sub>BSUVH</sub>	V <sub>CC</sub> supply under-voltage lockout hysteresis			0.6		
I <sub>LK</sub>	Offset supply leakage current	V <sub>B</sub> =V <sub>S</sub> =600V			50	
$I_{QBS}$	Quiescent V <sub>BS</sub> supply current	V <sub>IN</sub> =0V or 5V		45	120	μΑ
I <sub>QCC</sub>	Quiescent V <sub>CC</sub> supply current	V <sub>IN</sub> =0V or 5V		70	180	
I <sub>PBS</sub>	Operating V <sub>BS</sub> supply current	f <sub>IN</sub> =20kHz,rms value			600	пΔ
I <sub>PCC</sub>	Operating V <sub>CC</sub> supply current	f <sub>IN</sub> =20kHz,rms value			600	μΑ
$V_{IH}$	Logic "1" input voltage		2.9			
$V_{IL}$	Logic "0" input voltage				8.0	V
V <sub>OH</sub>	High-level output voltage, $V_{BIAS}$ - $V_{O}$	I <sub>O</sub> =20mA			1.0	•
$V_{OL}$	Low-level output voltage, V <sub>O</sub>	10-20111A			0.6	
$I_{\text{IN+}}$	Logic "1" input bias current	V <sub>IN</sub> =5V		10	20	μΑ
I <sub>IN-</sub>	Logic "0" input bias current	V <sub>IN</sub> =0V		1.0	2.0	μΑ
I <sub>O+</sub>	Output high short-circuit pulsed current	$V_O=0V$ , $V_{IN}=5V$ with PW<10 $\mu$ s	250	350		mA
I <sub>O-</sub>	Output low short-circuit pulsed current	$V_O=15V$ , $V_{IN}=0V$ with PW<10 $\mu$ s	500	650		
V <sub>S</sub>	Allowable negative $V_S$ pin voltage for HIN signal propagation to HO			-9.8	-7.0	V

# **Dynamic Electrical Characteristics**

 $V_{BIAS}\left(V_{CC},\,V_{BS}\right)=15.0V,\,V_{S}=COM,\,C_{L}=1000pF\,\,and,\,T_{A}=25^{\circ}C,\,unless\,\,otherwise\,\,specified.$ 

Symbol	Characteristics	Test Condition	Min.	Тур.	Max.	Unit
t <sub>on</sub>	Turn-on propagation delay	V <sub>S</sub> =0V	100	170	300	
t <sub>off</sub>	Turn-off propagation delay	V <sub>S</sub> =0V or 600V <sup>(5)</sup>	100	200	300	
t <sub>r</sub>	Turn-on rise time		20	60	140	ns
t <sub>f</sub>	Turn-off fall time			30	80	
MT	Delay matching, HS & LS turn-on/off				50	

#### Note:

5. This parameter guaranteed by design.

## **Typical Characteristics**

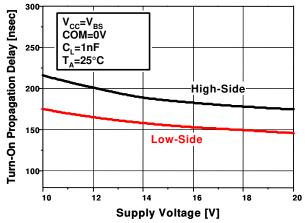


Figure 4. Turn-On Propagation Delay vs. Supply Voltage

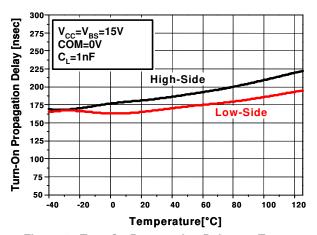


Figure 5. Turn-On Propagation Delay vs. Temp.

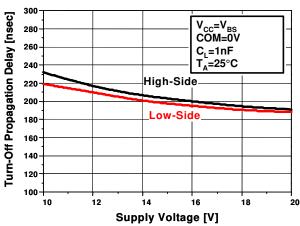


Figure 6. Turn-Off Propagation Delay vs. Supply Voltage

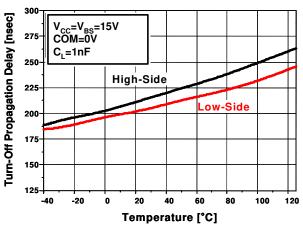


Figure 7. Turn-Off Propagation Delay vs. Temp.

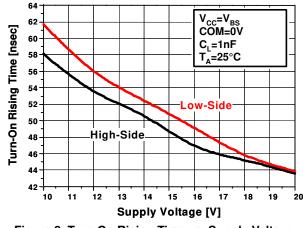


Figure 8. Turn-On Rising Time vs. Supply Voltage

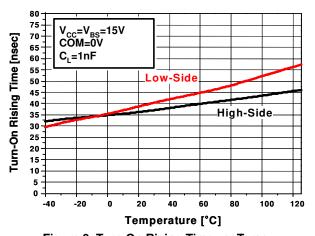


Figure 9. Turn-On Rising Time vs. Temp.

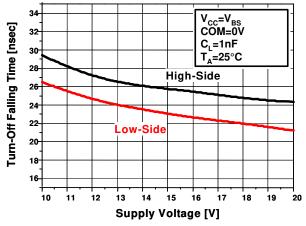


Figure 10. Turn-Off Falling Time vs. Supply Voltage

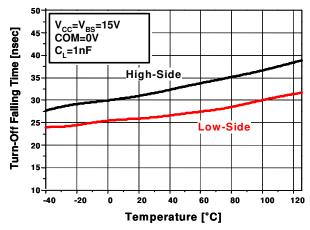


Figure 11. Turn-Off Falling Time vs. Temp.

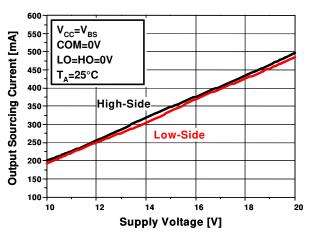


Figure 12. Output Sourcing Current vs. Supply Voltage

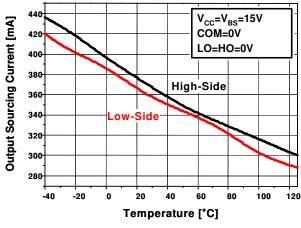
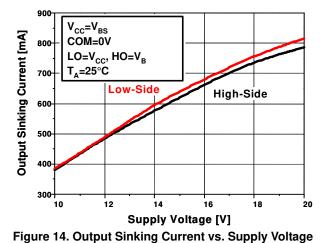


Figure 13. Output Sourcing Current vs. Temp



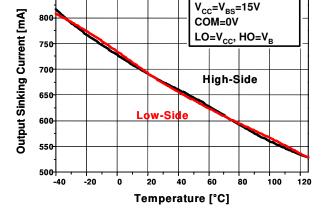


Figure 15. Output Sinking Current vs. Temp.

850-

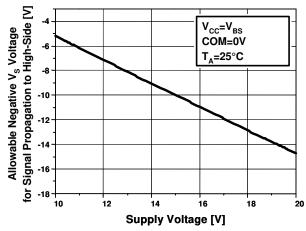


Figure 16. Allowable Negative V<sub>S</sub> Voltage for Signal Propagation to High Side vs. Supply Voltage

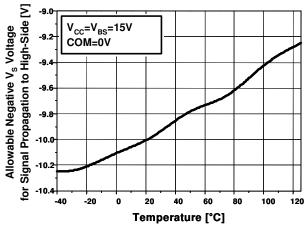


Figure 17. Allowable Negative V<sub>S</sub> Voltage for Signal Propagation to High Side vs. Temp.

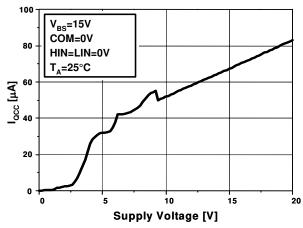


Figure 18. I<sub>QCC</sub> vs. Supply Voltage

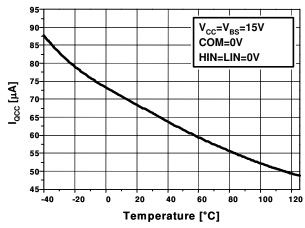


Figure 19. I<sub>QCC</sub> vs. Temp.

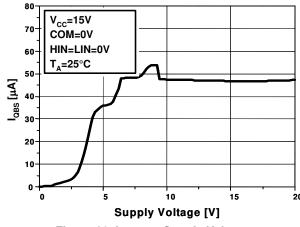


Figure 20. I<sub>QBS</sub> vs. Supply Voltage

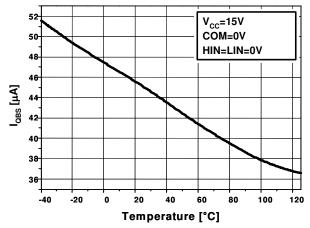


Figure 21. I<sub>QBS</sub> vs. Temp.

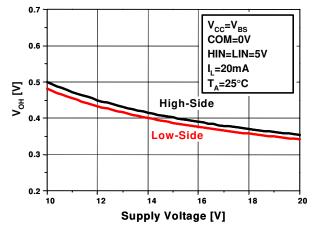


Figure 22. High-Level Output Voltage vs. Supply Voltage

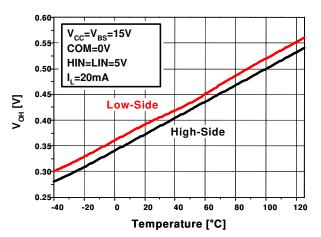


Figure 23. High-Level Output Voltage vs. Temp.

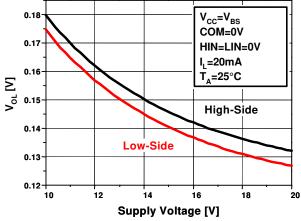


Figure 24. Low-Level Output Voltage vs. **Supply Voltage** 

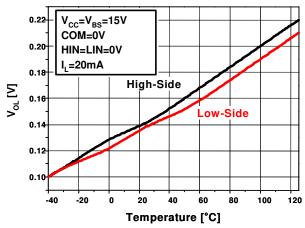


Figure 25. Low-Level Output Voltage vs. Temp.

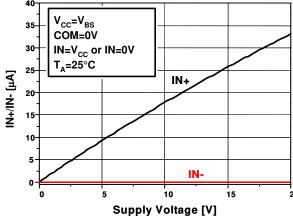


Figure 26. Input Bias Current vs. Supply Voltage

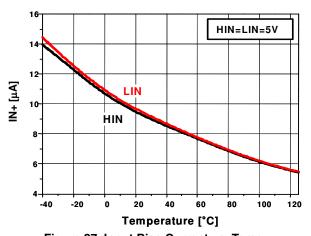


Figure 27. Input Bias Current vs. Temp.

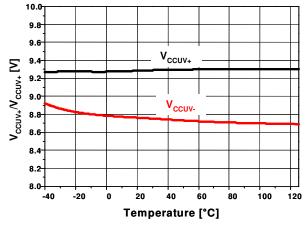


Figure 28. V<sub>CC</sub> UVLO Threshold Voltage vs. Temp.

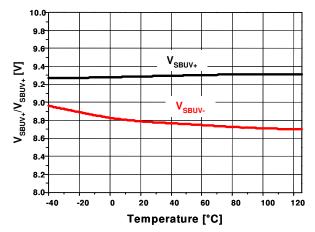


Figure 29.  $V_{BS}$  UVLO Threshold Voltage vs. Temp.

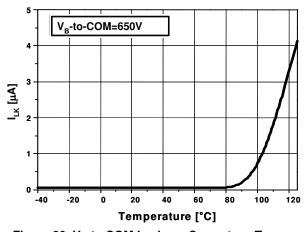


Figure 30.  $V_B$  to COM Leakage Current vs. Temp.

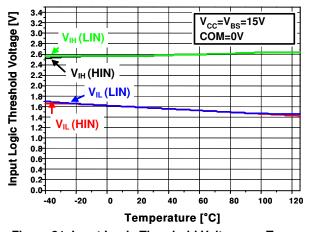


Figure 31. Input Logic Threshold Voltage vs. Temp.

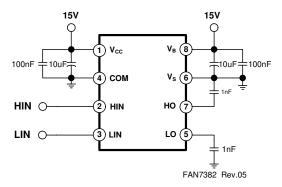


Figure 32. Switching Time Test Circuit

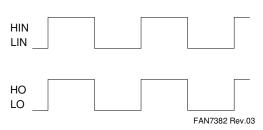


Figure 33. Input / Output Timing Diagram

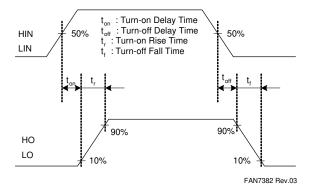


Figure 34. Switching Time Waveform Definition

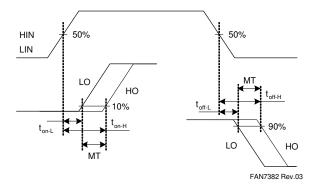
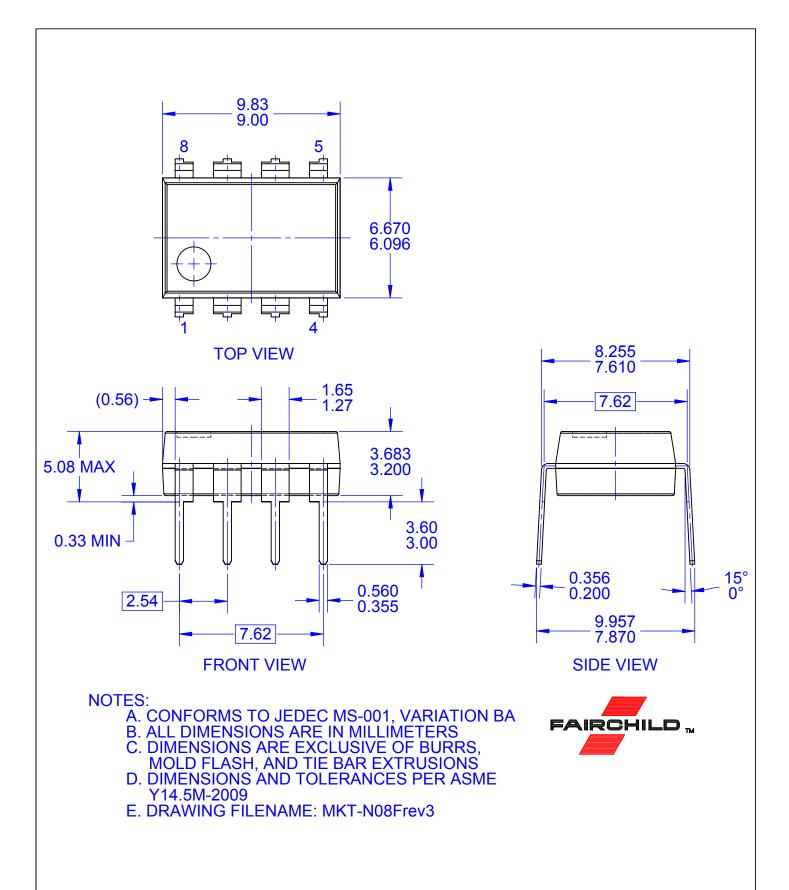
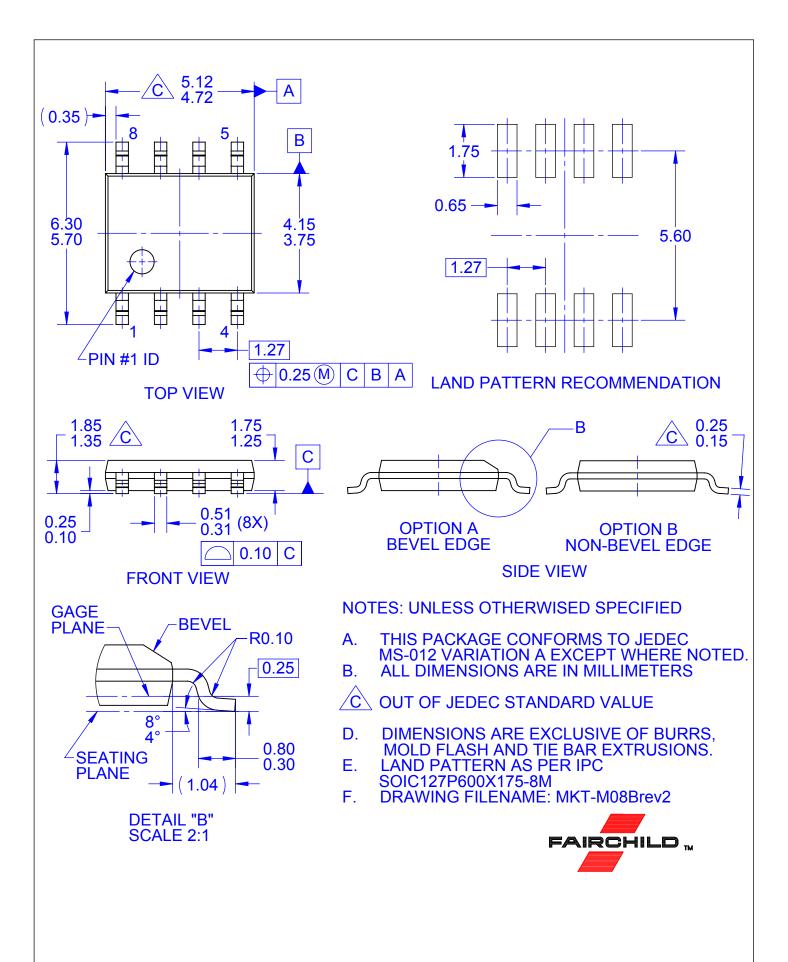
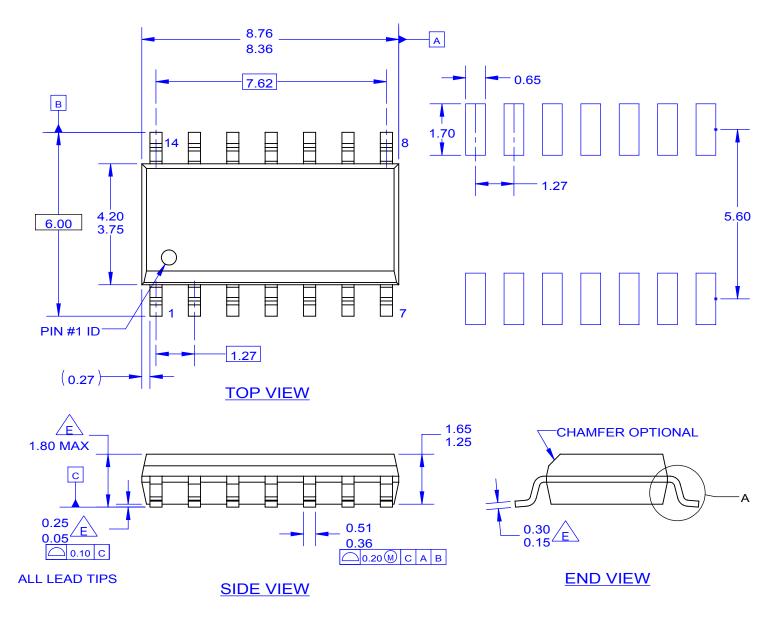


Figure 35. Delay Matching Waveform Definition

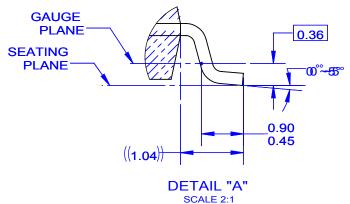






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- B. ALL DIMENSIONS ARE IN MILLIMETERS.
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- D. DIMENSIONS AND TOLERANCES AS PER ASME  $\land$  Y14.5-1994.
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